

NPN SILICON RF TRANSISTOR

NE85639 / 2SC4093 JEITA Part No.

NPN EPITAXIAL SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW-NOISE AMPLIFICATION 4-PIN MINIMOLD

DESCRIPTION

The NE85639 / 2SC4093 is a NPN silicon epitaxial transistor designed for low noise amplifier at VHF, UHF and CATV band.

It has large dynamic range and good current characteristics, and is contained in a 4-pin minimold package which enables high-isolation gain.

FEATURES

· Low Noise

NF = 1.1 dB TYP. @ VcE = 10 V, Ic = 7 mA, f = 1 GHz

· High Power gain

 $|S_{21e}|^2 = 13 \text{ dB TYP.}$ @ VcE = 10 V, Ic = 20 mA, f = 1 GHz

- Maximum available power gain: MAG = 14.2 dB TYP. @ VcE = 10 V, Ic = 20 mA, f = 1 GHz
- · 4-pin minimold Package

★ ORDERING INFORMATION

Part Number	Quantity	Supplying Form		
NE85639-A	50 pcs (Non reel)	• 8 mm wide embossed taping		
2SC4093-A		Pin 3 (Base), Pin 4 (Emitter) face to perforation side of the tape		
NE85639-T1-A	3 kpcs/reel	7 • Fill 3 (base), Fill 4 (Effiller) face to perforation side of the tape		
2SC4093-T1-A				

Remark To order evaluation samples, contact your nearby sales office.

The unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	20	V
Collector to Emitter Voltage	Vceo	12	V
Emitter to Base Voltage	VEBO	3.0	V
Collector Current	lc	100	mA
Total Power Dissipation	P _{tot} Note	200	mW
Junction Temperature	Tj	150	°C
Storage Temperature	T _{stg}	-65 to +150	°C

Note Free air

Caution: Observe precautions when handling because these devices are sensitive to electrostatic discharge

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit	
DC Characteristics							
Collector Cut-off Current	Ісво	VcB = 10 V, IE = 0 mA	-	-	1.0	μΑ	
Emitter Cut-off Current	ІЕВО	VEB = 1 V, Ic = 0 mA	_	-	1.0	μΑ	
DC Current Gain	hfe Note 1	Vce = 10 V, Ic = 20 mA	50	120	250	-	
RF Characteristics							
Gain Bandwidth Product	f⊤	VcE = 10 V, Ic = 20 mA	_	7.0	-	GHz	
Insertion Power Gain	S _{21e} ²	Vce = 10 V, Ic = 20 mA, f = 1.0 GHz	11	13	_	dB	
Noise Figure	NF	Vce = 10 V, Ic = 7 mA, f = 1.0 GHz	-	1.1	2.0	dB	
Reverse Transfer Capacitance	Cre Note 2	VcB = 10 V, IE = 0 mA, f = 1.0 MHz	-	0.6	0.95	pF	

Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

2. Collector to base capacitance when the emitter grounded

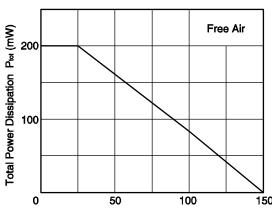
hfe CLASSIFICATION

Rank	R26/RBF Note	R27/RBG Note	R28/RBH Note	
Marking	R26	R27	R28	
Range	50 to 100	80 to 160	125 to 250	

Note Old Specification / New Specification

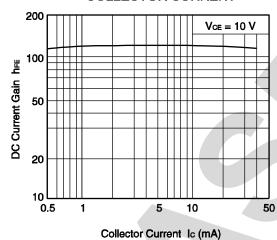
TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)



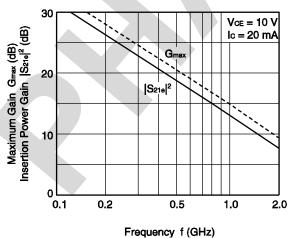


Ambient Temperature TA (°C)

DC CURRENT GAIN vs. COLLECTOR CURRENT

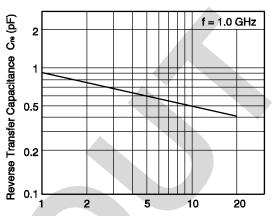


MAXIMUM GAIN/INSERTION POWER GAIN vs. FREQUENCY



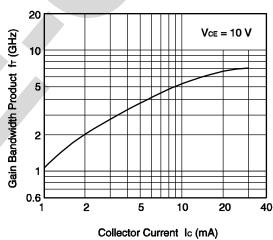
Remark The graphs indicate nominal characteristics.

REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE

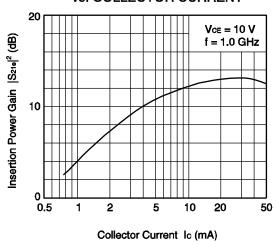


Collector to Base Voltage VcB (V)

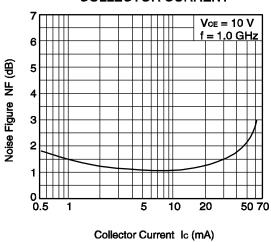
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



INSERTION POWER GAIN vs. COLLECTOR CURRENT



NOISE FIGURE vs. COLLECTOR CURRENT



Remark The graph indicates nominal characteristics.

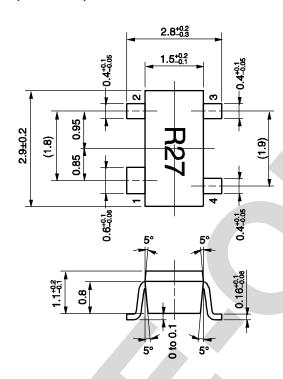
★ S-PARAMETERS

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- · Click here to download S-parameters.
- [RF and Microwave] ® [Device Parameters]
- URL http://www.necel.com/microwave/en/



★ PACKAGE DIMENSIONS

4-PIN MINIMOLD PACKAGE (UNIT: mm)



PIN CONNECTIONS

- 1. Collector
- 2. Emitter
- 3. Base
- 4. Emitter

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